





Alliance for Astroparticle Physics

# **Production of CaWO4 Crystals for the CRESST Experiment & Development of Neganov-Luke Amplified Cryogenic Light Detectors**

HAP Dark Matter 2015

Michael Willers *TU München & Excellence Cluster Universe*

22.09.2015

# **Production of CaWO4 Crystals for the CRESST Experiment**

# CRESST III

- Already introduced by H. Kluck
- Focus on low-mass WIMPs

(see also: Probing low WIMP masses with the next generation of CRESST detectors, arXiv 1503.08065)

- → important factors: Performance (Threshold) & **Radiopurity**
- New, fully scintillating, detector modules (crystal mass  $\sim$  25g)





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- Before CRESST-II Phase 2: only commercial CaWO<sub>4</sub> crystals (Russia & Ukraine)
	- Difficult: influence on selection of raw materials
	- No influence on crystal growth parameters
- Since ~ 2011: in-house production of CaWO<sub>4</sub> crystals at TUM for *CRESST & EURECA*<sup>\*</sup>
	- *Full control over raw materials (screening & selection)*
	- *Full control of growth / post-growth treatment parameters!*
- Dedicated Czochralski furnace for CaWO<sub>4</sub> crystals





\* A. Erb and J.C. Lanfranchi, Growth of high-purity scintillating CaWO4 single crystals for the lowtemperature direct dark matter search experiments CRESST-II and EURECA, CrystEngComm, 2013

#### M. Willers **According to According the HAP Dark Matter 2015**



- Steady development towards complete in-house production of CaWO<sub>4</sub> crystals  $\checkmark$ 
	- Production of raw powder:  $CaCO<sub>3</sub> + WO<sub>3</sub> \rightarrow CaWO<sub>4</sub> + CO<sub>2</sub>$
	- Crystal growth (Czochralski method) in Rh crucible (99%Ar / 1% O2)
	- Post growth treatment (annealing) to improve optical quality (100%  $O<sub>2</sub>$ )
	- Cutting & polishing of crystals
- Dedicated oven & powder grinding machine to produce CaWO<sub>4</sub> powder
- Dedicated annealing oven
- CRESST-II Phase 2 : 4 TUM-grown crystals CRESST-III : majority of crystals foreseen to be TUM-grown



- Production of ray
- 
- 
- Cutting & polishi
- 
- Dedicated annealing
- $\bullet$  CRESST-II Phase 2  $\circ$





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# Improved Radiopurity: TUM40

Total  $\alpha$  - Activities (1.5 - 7 MeV)

### $e$ -/ $\gamma$  Background events below 50 keV



TUM40: 3.07 ± 0.11 mBq/kg commercial crystals: 3 - 107 mBq/kg (Münster et al., JCAP05(2014)018)

TUM40: 3.51 / (keV kg day) commercial crystals: 6 - 30 / (keV kg day) (Strauss et al., JCAP06(2015)030)

Significant improvement in radiopurity!

For TUM40 results see: EPJC (2015) 75:352

## Further Improvement of Radiopurity

### recrystallisation of CaWO<sub>4</sub> crystals

- growth of multiple crystals (segregation of impurities during crystal growth)
- cleaning of crucible / removal of remaining melt
- recrystallisation of produced crystals
- $\rightarrow$  growth of crystal with improved radiopurity
- chemical cleaning of raw materials
	- CaWO4 powder cannot be cleaned (due to chemical / physical properties)  $\rightarrow$  cleaning of raw materials (currently CaCO<sub>3</sub>)
	- Preliminary results: U extraction factor ~ *5000*, Th extraction factor ~ *1000* (detailed ICP-MS / HPGe measurements ongoing, check that no new impurities are introduced!)
- $\rightarrow$  growth of crystal with improved radiopurity
- both methods currently under investigation (PhD thesis A. Münster (in preparation))  $\rightarrow$  operation of crystal with further improved radiopurity planned for CRESST III

### **Further activities:**

- $\cdot$  Study influence of crystal growth / annealing on optical properties of CaWO<sub>4</sub> crystals (PhD thesis, A. Münster, in preparation)
- $\cdot$  Investigate radiopurity of CaWO<sub>4</sub> via scintillation spectroscopy

(PhD thesis, M. v. Sivers, TUM 2014 (now University of Bern))

 $\cdot$  Investigate scintillation mechanisms in CaWO<sub>4</sub>

(PhD thesis S. Roth, TUM 2014 (now Queens University, Kingston), in collaboration with A. Ulrich, TUM E12)

• Investigate scintillator non-proportionality

(Master thesis C. Bruhn, TUM 2015)

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### **Summary:**

- Complete in-house production of CaWO4 crystals for CRESST / EURECA $\checkmark$
- Significant improvement in radiopurity  $\checkmark$  (+ further potential for improvement!)
- Ongoing activities to study scintillation mechanism & optical properties

# **Development of Neganov-Luke Amplified Cryogenic Light Detectors**

 $\rightarrow$  Goal: Improve sensitivity (threshold / resolution) of cryogenic light detectors relevant for background suppression in both DM ( $e$ - $\gamma$ / nuclear-recoil separation) and 0 $\nu\beta\beta$  ( e- /  $\alpha$  separation ) experiments!



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➝ Drifting of charge carriers in Electric field leads to increased phonon signal

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G_{\it th}=1+\frac{eV_{NL}}{E_{\it ph}/\eta}
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Ideally: no increase in el. noise  $\rightarrow$  improvement in S/N ratio  $\rightarrow$  improved sensitivity

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#### A typical silicon-based NL light detector:

*light absorber:*  $20 \times 20 \times 0.5$  mm<sup>3</sup>, p-type,  $\rho > 10$ k $\Omega$ cm *aluminum electrodes ~* 20 mm  $\times$  0.2 mm  $\times$  250 nm, d ~ 6-18 mm ( produced using a photolithographic shadow mask and Ar-Sputtering / EBE of Al )



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- Typical NL voltages:  $\sim$  70 150 V
- NL amplification:  $\sim$  10 @ 70V ( $\sim$  25 expected)
- additionally: reduction of amplification with time solved now  $\checkmark$
- Currently under Investigation: Why can we apply "only" up to 150V? Why is the amplification lower than expected?

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# Neganov-Luke: Effective Gain

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G_{\textit{eff}} = 1 + \frac{e V_{\textit{eff}}(t)}{E_{\textit{ph}}/\eta} \cdot \frac{l_{\textit{drift}}}{d}
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Stark et. al, NIM A 545 (2005)



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*Reduced drift length (ldrift< d):* 

• trapping of charge carriers  $(\rightarrow G_{\text{eff}} < G_{\text{th}})$ 

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• trapping of charge carriers ( $\rightarrow$  G<sub>eff</sub> < G<sub>th</sub>)

*Reduction of signal amplitude:* 

- Accumulation of drifted charge carriers close to aluminum electrodes  $\rightarrow$  Reduction of V<sub>eff</sub> (& G<sub>eff</sub>) over time
- Annealing of substrates (PhD s. Roth TUM 2014)  $\rightarrow$  Significant improvement



Isaila et al. Physics Letters B 716 (2012) PhD Thesis S. Roth, TUM 2014

# Neganov-Luke Light Detectors - Planar Electrode Geometry



- Planar electrode geometry (shallow (implanted) ohmic contacts) V<sub>NL</sub> applied between top/bottom face of light detector
- ➝ Drift of e/h pairs through bulk / *no drift across surface* of substrate!
- Very high electric fields possible  $($   $\sim$  6.5 kV/cm)
- First measurements promising: no increase in noise / linear amplification / no charge trapping
- Detailed measurements in preparation!

In collaboration with X. Defay (Excellence Cluster Universe & TUM) "Cryogenic silicon detectors with implanted contacts for the detection of visible photons using the Neganov-Luke Effect", arXiv 1509.06266

# Application: Background Suppression in TeO<sub>2</sub> Crystals

- $130$ Te (TeO<sub>2</sub>) promising 0νββ candidate
- $\cdot$   $\alpha$ -events expected to be dominant background contribution in next-gen. experiments
- future-gen. experiments (CUPID arxiv 1504.03599) plan to employ active background suppression techniques
	- $\rightarrow$  detection of Cherenkov photons for e- /  $\alpha$  discrimination (expected signal at  $Q_{\beta\beta}(130 \text{ Te})$ : ~ 100eV)



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@TUM: first measurements showing feasibility of Cherenkov detection from TeO<sub>2</sub> using NL light detectors (2015 JINST 10 P03003)



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# **Thank you for your attention!**